NSN 5961-00-160-6718

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-160-6718 **Inclosure Material:** Ceramic **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.096 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes average forward current averaged over a full 60-hz cycle and 150.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli